# NSN 5962-01-109-2426

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AeroBase Group

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### Body Length: 1.230 inches Body Width: Between 0.580 inches and 0.620 inches Body Height: Between 0.150 inches and 0.180 inches Maximum Power Dissipation Rating:

1.0 watts

#### **Operating Tempurature Range:**

+0.0/+70.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and monolithic and positive outputs and high speed and 3-state output

#### **Inclosure Material:**

Ceramic and glass

### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

N-type metal oxide-semiconductor logic

#### Input Circuit Pattern:

13 input

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

7.0 volts power source

#### **Time Rating Per Chacteristic:**

400.00 nanoseconds propagation delay time, low to high level output and 400.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### **Memory Capacity:**

Unknown

#### **Test Data Document:**

28480-1818-0209 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### Terminal Type And Quantity:

24 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

Demilitarization:

Yes - demil/mli

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